

**LISTING OF CLAIMS:**

1 – 13. (Canceled)

14. (Currently amended): An electronic device comprising:

a first base comprising a first conductive portion and a second conductive portion, said first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential, said second conductive portion being electrically connected to said first conductive portion and containing a second metal or metal compound having a second equilibrium electrode potential;

an underlying layer formed on said first base; and

a reflective portion formed on a surface of said underlying layer, said reflective portion comprising a plurality of projections or recesses;

wherein said underlying layer comprises:

coating portions provided at positions corresponding to said plurality of projections or recesses, wherein said coating portion comprises chromium molybdenum oxide; and

an underlying layer main portion formed using photosensitive material, said underlying layer main portion covering said coating portions.

15. (Currently amended): An electronic device as claimed in claim 14, wherein said first base comprises[[:] a supporting member,[:] and wherein said first conductive portion is formed on said supporting member,[:] and said second conductive portion is formed so as to lie on said first conductive portion.

16. (Original): An electronic device as claimed in claim 15, wherein said first conductive portion is formed on an insulating film.

17. (Currently amended): An electronic device as claimed in claim 14, wherein said first base comprises:

a supporting member;

said first conductive portion formed on said supporting member;

wherein said ~~an~~ insulating film having a hole for electrically connecting said first and second conductive portions; and

said second conductive portion electrically connected to said first conductive portion through said hole.

18. (Currently amended): An electronic device as claimed in claim 16, wherein said insulating film comprises ~~has~~ silicon nitride or silicon dioxide, ~~and wherein said coating portion has chromium molybdenum oxide.~~

19. (Currently amended): An electronic device comprising:

a first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential,

a second conductive portion containing a second metal or metal compound having a second equilibrium electrode potential, said second conductive portion being electrically connected to said first conductive portion and;

a sacrificial electrode electrically connected to said first and second conductive portions,  
wherein said sacrificial electrode and said first conductive portion are different portions form  
from same layer on a substrate.

20. (Original): An electronic device as claimed in claim 19, said sacrificial electrode is directly connected to one of said first and second conductive portions.

21. (Original): An electronic device as claimed in claim 19, said sacrificial electrode and one of said first and second conductive portions are integrally formed.

22. (Previously presented): An electronic device as claimed in claim 19, wherein said sacrificial electrode contains said first or second metal or metal compound.

23. (Previously presented): An electronic device as claimed in claim 19, wherein said second conductive portion lies on the top of said first conductive portion.

24. (Currently amended): An electronic device as claimed in claim 15, wherein a combination of said first and second conductive portions form forms at least part of a gate electrode, a gate bus, a source electrode or a source bus.

25. (Currently amended): An electronic device as claimed in claim 24, wherein said first conductive portion comprises has molybdenum as said first metal or metal compound, and

wherein said second conductive portion comprises ~~has~~ aluminum as said second metal or metal compound.

26. (Previously presented): An electronic device as claimed in claim 19, wherein said first conductive portion is electrically connected to said second conductive portion via a hole of an insulating film.

27. (Currently amended): An electronic device ~~as claimed in claim 15~~ comprising:   
a first base comprising a first conductive portion and a second conductive portion, said first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential, said second conductive portion being electrically connected to said first conductive portion and containing a second metal or metal compound having a second equilibrium electrode potential, wherein said first base comprises a supporting member, wherein said first conductive portion is formed on said supporting member and said second conductive portion is formed so as to lie on said first conductive portion, wherein said first conductive portion is at least part of a gate terminal, and wherein said second conductive portion is at least part of a gate bus;

an underlying layer formed on said first base, wherein said underlying layer comprises coating portions provided at positions corresponding to said plurality of projections or recesses; and an underlying layer main portion formed using photosensitive material, said underlying layer main portion covering said coating portions; and  
a reflective portion formed on a surface of said underlying layer, said reflective portion comprising a plurality of projections or recesses.

28. (Currently amended): An electronic device as claimed in claim 15 comprising:  
a first base comprising a first conductive portion and a second conductive portion, said first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential, said second conductive portion being electrically connected to said first conductive portion and containing a second metal or metal compound having a second equilibrium electrode potential, wherein said first base comprises a supporting member, wherein said first conductive portion is formed on said supporting member and said second conductive portion is formed so as to lie on said first conductive portion, wherein said first conductive portion is at least part of a source terminal, and wherein said second conductive portion is at least part of a gate electrode of an ESD transistor;

an underlying layer formed on said first base, wherein said underlying layer comprises coating portions provided at positions corresponding to said plurality of projections or recesses; and an underlying layer main portion formed using photosensitive material, said underlying layer main portion covering said coating portions; and

a reflective portion formed on a surface of said underlying layer, said reflective portion comprising a plurality of projections or recesses.

29. (Currently amended): An electronic device as claimed in claim 27, wherein said first conductive portion comprises has indium oxide as said first metal or metal compound, and wherein said second conductive portion comprises has aluminum or molybdenum as said second metal or metal compound.

30. (Original): An electronic device as claimed in claim 19, wherein said electronic device comprises a third conductive portion, and wherein said first conductive portion covers a part of said third conductive portion.

31. (Original): An electronic device as claimed in claim 30, wherein said third conductive portion is at least part of a gate terminal.

32. (Previously presented): An image display device comprising an electronic device as claimed in claim 14.

33. (New): An electronic device comprising:

a first base comprising a first conductive portion, said first conductive portion containing a first metal or metal compound having a first equilibrium electrode potential, wherein said first conductive portion is formed on an insulating film;

an underlying layer formed on said first base; and

a reflective portion formed on a surface of said underlying layer, said reflective portion comprising a plurality of projections or recesses;

wherein said underlying layer comprises:

coating portions provided at positions corresponding to said plurality of projections or recesses, wherein said coating portion comprises chromium molybdenum oxide; and

an underlying layer main portion formed using photosensitive material, said underlying layer main portion covering said coating portions.

34. (New): An electronic device as claimed in claim 33, wherein said first base comprises a support member, and wherein said insulating film is formed on said supporting member, and said first conductive portion is formed on said insulating film.

35. (New): An electronic device as claimed in claim 33, wherein said first conductive portion is at least part of a gate terminal.

36. (New): An electronic device as claimed in claim 33, wherein said first conductive portion is at least part of a source terminal.

37. (New): An electronic device as claimed in claim 33, wherein said insulating film comprises silicon nitride or silicon dioxide.